



# **isc Silicon NPN Power Transistor**

### **DESCRIPTION**

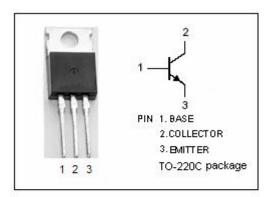
- · Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= 400V(Min)
- · Fast Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

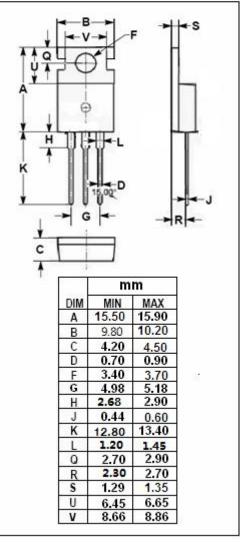
## **APPLICATIONS**

- Switching regulator and high voltage switching applications.
- · High speed DC-DC converter applications.



SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	500	V
V <sub>CEO</sub>	Collector-Emitter Voltage	400	V
V <sub>EBO</sub>	Emitter-Base Voltage	7	V
Ic	Collector Current-Continuous	5	А
I <sub>B</sub>	Base Current-Continuous	1	А
Pc	Collector Power Dissipation @ T <sub>C</sub> =25°C	40	w
TJ	Junction Temperature	150	$^{\circ}$
T <sub>stg</sub>	Storage Temperature Range	-55~150	$^{\circ}$







# isc Silicon NPN Power Transistor

2SC2553

### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

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SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT		
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10mA; I <sub>E</sub> = 0	400			V		
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = 1mA; I <sub>E</sub> = 0	500			V		
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 5A; I <sub>B</sub> = 1A			1.0	V		
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 5A; I <sub>B</sub> = 1A			1.5	V		
Ісво	Collector Cutoff Current	V <sub>CB</sub> = 400V; I <sub>E</sub> = 0			100	μА		
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 7V; I <sub>C</sub> = 0			1.0	mA		
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 3A; V <sub>CE</sub> = 5V	12					
h <sub>FE-2</sub>	DC Current Gain	Ic= 5A; Vc= 5V	8					
Switching times								
tr	Rise Time				1.0	μ <b>S</b>		
t <sub>stg</sub>	Storage Time	$I_{B1}$ = $-I_{B2}$ = 0.4A; $R_L$ = 50 $\Omega$ ; $V_{CC}$ $\approx$ 200V			2.5	μ <b>S</b>		
t <sub>f</sub>	Fall Time				1.0	μS		

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